

Guaranteed Operating Ranges

Symbol	Parameter ¹	Unit	Min.	Typ.	Max.
V _{CC}	Positive DC Supply Voltage	V	4.5	5.0	5.5
V _{EE}	Negative DC Supply Voltage	V	-8.5	-5.0	-4.5
V _{OPT} ²	Optional DC Output Supply Voltage	V	0	1.0	2.0
V _{OPT} -V _{EE}	Negative Supply Voltage Range	V	4.5	6.5	11.0
V _{CC} -V _{EE}	Positive to negative Supply Range	V	9.0	10.0	14.0
T _A	Operating Ambient temperature	°C	-40	+25	+85
I _{OH}	DC Output Current - High	mA	—	—	-1.0
I _{OL}	DC Output Current - Low	mA	—	—	1.0
T _{rise} , T _{fall}	Maximum Input Rise or Fall Time	ns	—	—	500

1. All voltages are relative to GND.

2. V_{OPT} is grounded for most applications. To improve the intermodulation performance and the 1 dB compression point of GaAs control devices at low frequencies, V_{OPT} can be increased to between 1.0 and 2.0V. The nonlinear characteristics of the GaAs control devices will approximate performance at 500 MHz. It should be noted that the control current is on the GaAs MMICs will increase when positive controls are applied.

DC Characteristics over Guaranteed Operating Range

Symbol	Parameter	Test Conditions		Units	Min.	Typ.	Max.
V _{IH}	Input High Voltage	Guaranteed High Input Voltage		V	2.0	—	—
V _{IL}	Input Low Voltage	Guaranteed Low Input Voltage		V	—	—	0.8
V _{IH}	Output High Voltage	I _{OH} = -1 mA	V _{EE} = Max	V	V _{OPT} -0.1	—	—
V _{OL}	Output Low Voltage	I _{OL} = 1 mA	V _{EE} = Max	V	—	—	V _{EE} +0.1
I _{IN}	Input Leakage Current	V _{IN} = V _{CC} or GND	V _{EE} = Min	μA	—	.01	10
I _{CC}	Quiescent Supply Current	V _{CC} = Max V _{OPT} = Min or Max	V _{EE} = Min V _{IN} = V _{CC} or GND	μA	—	—	100
Δ I _{CC}	Additional Supply Current, per TTL Input pin	V _{CC} = Max	V _{IN} = V _{CC} -2.1V	mA	—	—	1.0

Handling Procedures

Please observe the following precautions to avoid damage:

Static Sensitivity

Silicon Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.

Truth Table

Input	Outputs	
C1	A	B
Logic "0"	V _{EE}	V _{OPT}
Logic "1"	V _{OPT}	V _{EE}

AC Characteristics Over Guaranteed Operating Range³

Symbol	Parameter	-55 to +25°C	≤+85°C	≤+125°C	Unit
T_{PLH}	Propagation Delay	22	25	30	ns
T_{PHL}	Propagation Delay	22	25	30	ns
T_{TLH}	Output Rising Transition Time	9.0	9.0	9.0	ns
T_{THL}	Output Falling Transition Time	8.0	8.0	8.0	ns
T_{skew}	Delay Skew, Output A to Output B	4.0	4.0	4.0	ns
C_{IN}	Input Capacitance	10	10	10	pF
C_{PDC}	Power Dissipation Capacitance ⁴	10	10	10	pF
C_{PDE}	Power Dissipation Capacitance ⁴	140	140	140	pF

3. $V_{CC} = 4.5V$, $V_{OPT} - V_{EE} = \text{min or max}$, $V_{OPT} = 0V$, $C_L = 25 \text{ pF}$, $T_{rise} = 6\text{ns}$, $T_{fall} = 6\text{ns}$. These conditions represent the worst case for slow delays.

4. Total Power Dissipation is calculated by the following formula: $PD = V_{CC}^2 f_{C_{PDC}} + (V_{OPT} - V_{EE})^2 f_{C_{PDE}}$

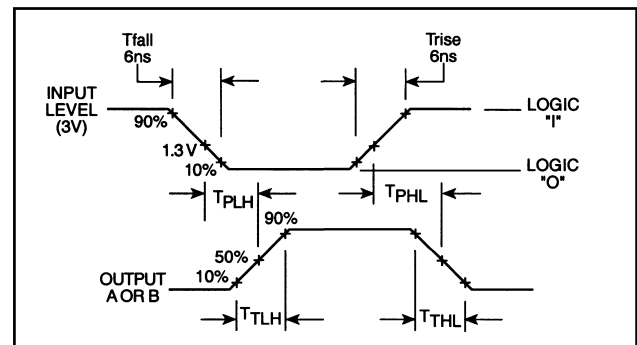
Absolute Maximum Ratings⁵

Symbol	Parameter	Min	Max	Unit
V_{CC}	Positive DC Supply Voltage	-0.5	7.0	V
V_{EE}	Negative DC Supply Voltage	-9.0	0.5	V
V_{OPT}	Optional DC Output Supply Voltage	-0.5	$V_{CC} + 0.5$	V
$V_{OPT} - V_{EE}$	Output to Negative Supply Voltage Range	-0.5	11.0	V
$V_{CC} - V_{EE}$	Positive to Negative Supply Voltage Range	-0.5	14.0	V
V_I	DC Input Voltage	-0.5	$V_{CC} + 0.5$	V
I_I	DC Input Current	-25	25	mA
V_O	DC Output Voltage	$V_{EE} - 0.5$	$V_{OPT} + 0.5$	V
P_D ⁶	Power Dissipation in Still Air	—	500	mW
V_O	DC Output Current	-25	25	mA
T_{STG}	Storage Temperature	-65	150	°C

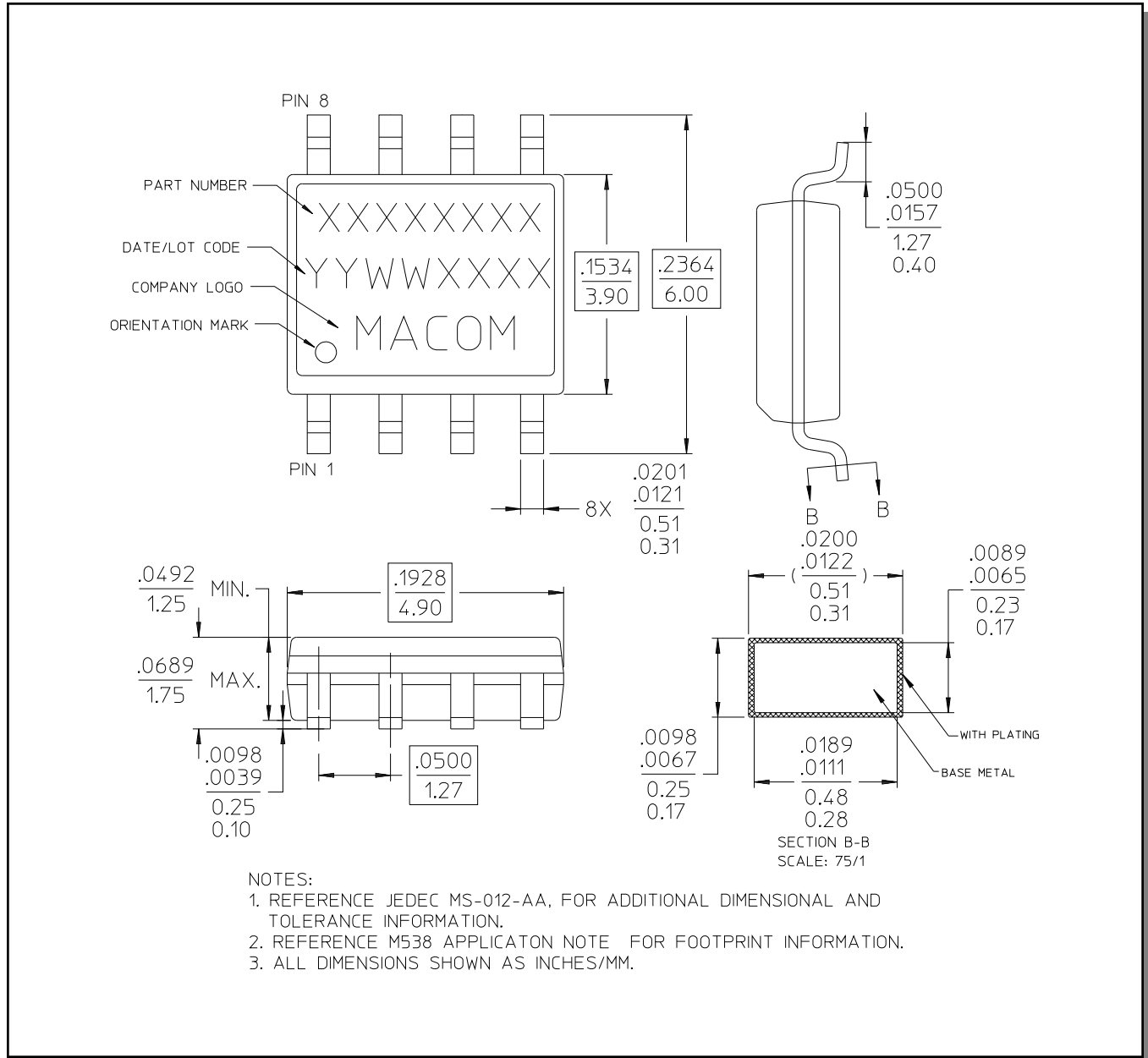
5. All voltages are referenced to GND. All inputs and outputs incorporate latch-up protection structures.

6. Derate -7 mW/°C from 65°C to 85°C.

Switching Waveforms



SOIC-8[†]



[†] Reference Application Note M538 for lead-free solder reflow recommendations.